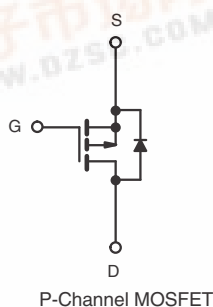
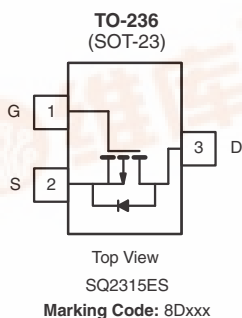


Automotive P-Channel 12 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	- 12
$R_{DS(on)}$ (Ω) at $V_{GS} = -4.5$ V	0.050
$R_{DS(on)}$ (Ω) at $V_{GS} = -2.5$ V	0.068
$R_{DS(on)}$ (Ω) at $V_{GS} = -1.8$ V	0.092
I_D (A)	- 5



FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Compliant to RoHS Directive 2002/95/EC
- AEC-Q101 Qualified^c
- Find out more about Vishay's Automotive Grade Product Requirements at: www.vishay.com/applications

AUTOMOTIVE GRADE



RoHS
COMPLIANT
HALOGEN
FREE

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and Halogen-free	SQ2315ES-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	- 12	V
Gate-Source Voltage		V_{GS}	± 8	
Continuous Drain Current	$T_C = 25$ °C	I_D	- 5	A
	$T_C = 125$ °C		- 3	
Continuous Source Current (Diode Conduction)		I_S	- 2.5	
Pulsed Drain Current ^a		I_{DM}	- 20	
Single Pulse Avalanche Current	L = 0.1 mH	I_{AS}	- 11	
Single Pulse Avalanche Energy			E_{AS}	6
Maximum Power Dissipation ^a	$T_C = 25$ °C	P_D	2	W
	$T_C = 125$ °C		0.67	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to + 175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^b	R_{thJA}	175	°C/W
Junction-to-Foot (Drain)		R_{thJF}	75	

Notes

- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR-4 material).
- Parametric verification ongoing.



SQ2315ES


www.vishay.com 供应商

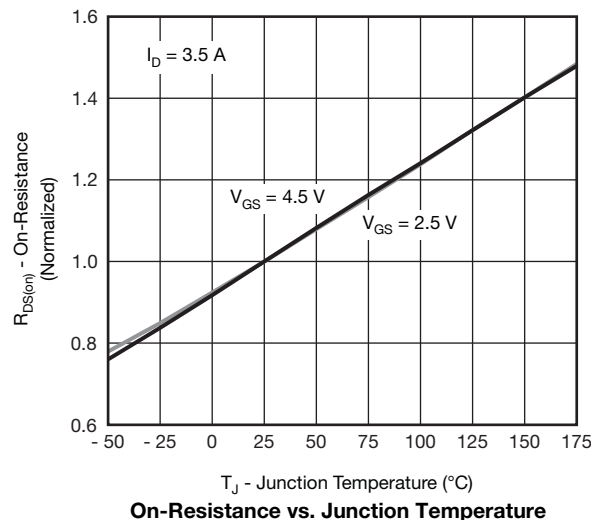
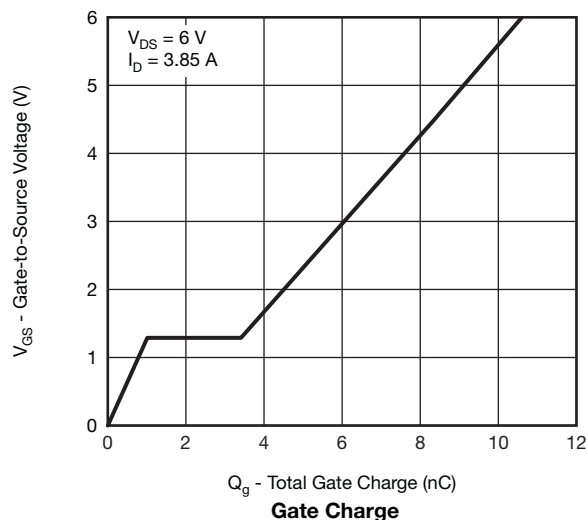
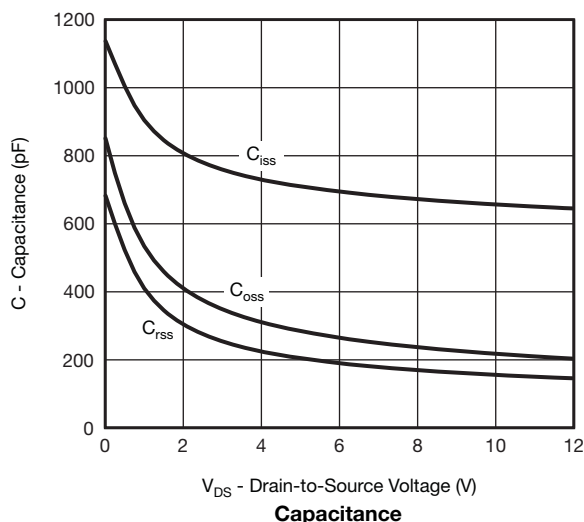
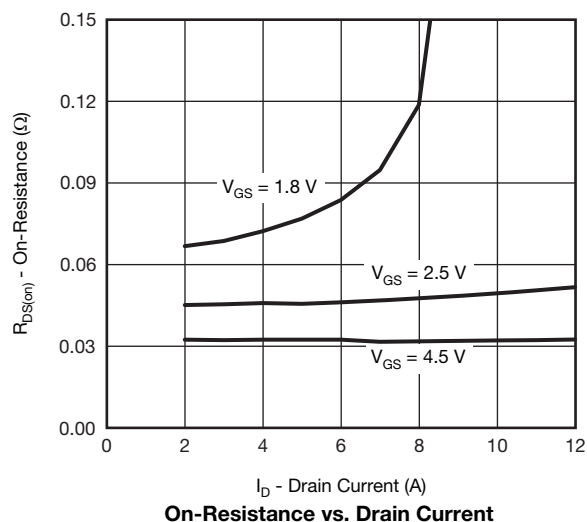
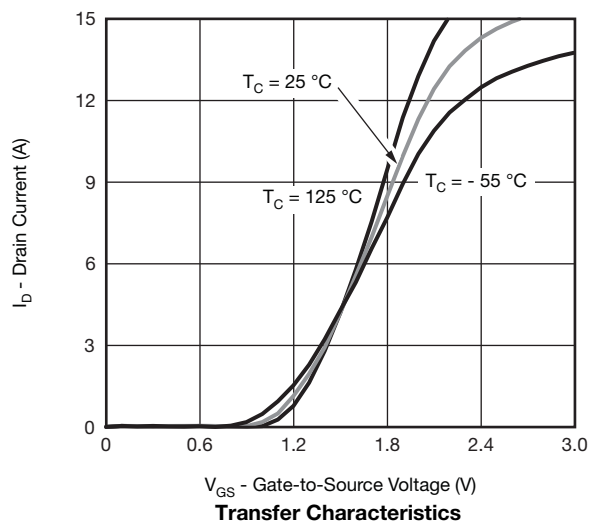
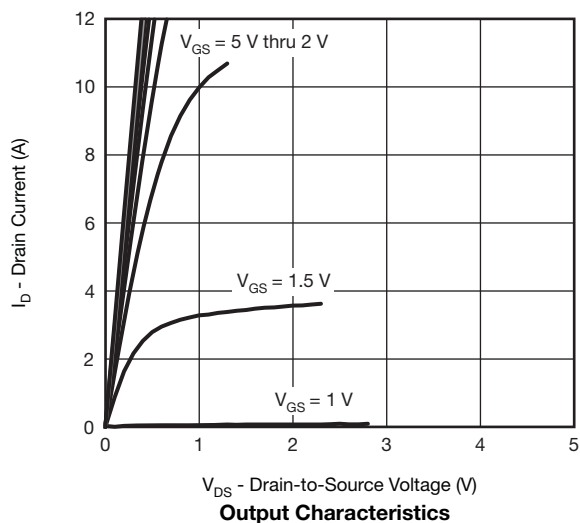
SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = - 250 μA		- 12	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA		- 0.45	-	- 1.0	
Gate-Source Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V		-	-	± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = - 12 V	-	-	- 1	μA
		V _{GS} = 0 V	V _{DS} = - 12 V, T _J = 125 °C	-	-	- 50	
		V _{GS} = 0 V	V _{DS} = - 12 V, T _J = 175 °C	-	-	- 150	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = - 4.5 V	V _{DS} ≤ - 5 V	- 10	-	-	A
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V	I _D = - 3.5 A	-	0.034	0.050	Ω
		V _{GS} = - 4.5 V	I _D = - 3.5 A, T _J = 125 °C	-	-	0.066	
		V _{GS} = - 4.5 V	I _D = - 3.5 A, T _J = 175 °C	-	-	0.075	
		V _{GS} = - 2.5 V	I _D = - 3 A	-	0.046	0.068	
		V _{GS} = - 1.8 V	I _D = - 2 A	-	0.067	0.092	
Forward Transconductance ^b	g _{fs}	V _{DS} = - 5 V, I _D = - 1.6 A		-	7	-	S
Dynamic^b							
Input Capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = - 6 V, f = 1 MHz	-	695	870	pF
Output Capacitance	C _{oss}			-	265	335	
Reverse Transfer Capacitance	C _{rss}			-	190	240	
Total Gate Charge ^c	Q _g	V _{GS} = - 4.5 V	V _{DS} = - 6 V, I _D = - 3.85 A	-	8.4	13	nC
Gate-Source Charge ^c	Q _{GS}			-	1	-	
Gate-Drain Charge ^c	Q _{GD}			-	2.4	-	
Turn-On Delay Time ^c	t _{d(on)}	V _{DD} = - 6 V, R _L = 1.6 Ω I _D ≅ - 3.85 A, V _{GEN} = - 4.5 V, R _g = 1 Ω		-	17	26	ns
Rise Time ^c	t _r			-	19	29	
Turn-Off Delay Time ^c	t _{d(off)}			-	28	42	
Fall Time ^c	t _f			-	13	20	
Source-Drain Diode Ratings and Characteristics^b							
Pulsed Current ^a	I _{SM}			-	-	- 20	A
Forward Voltage	V _{SD}	I _F = - 2 A, V _{GS} = 0 V		-	- 0.8	- 1.2	V

Notes

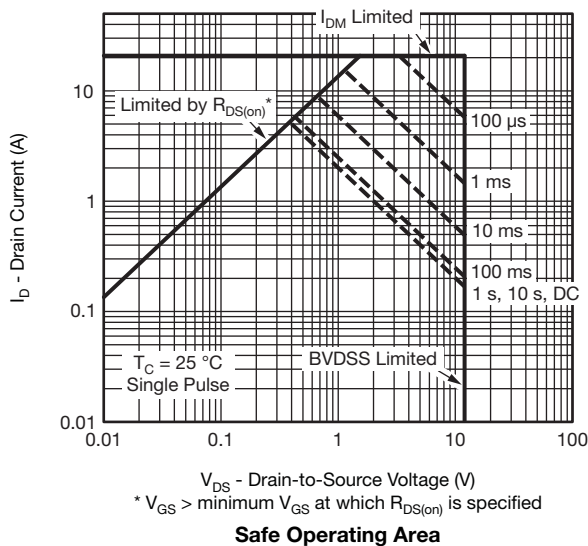
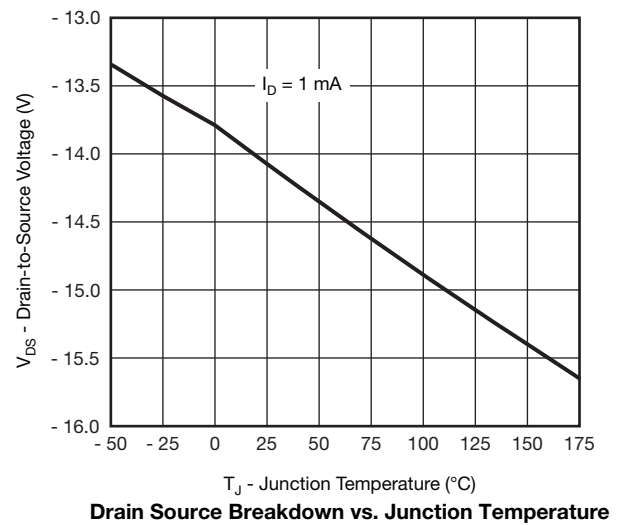
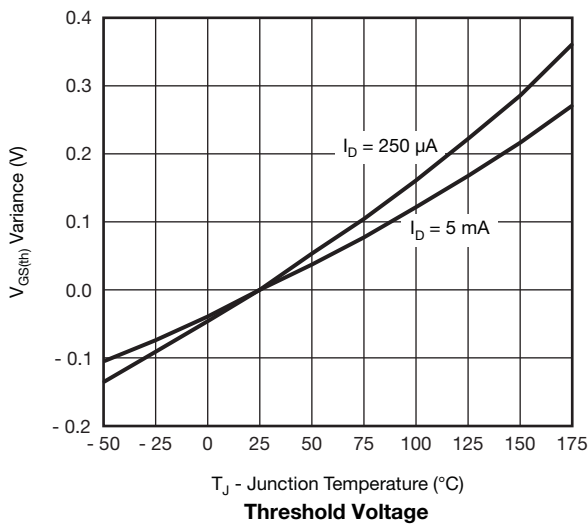
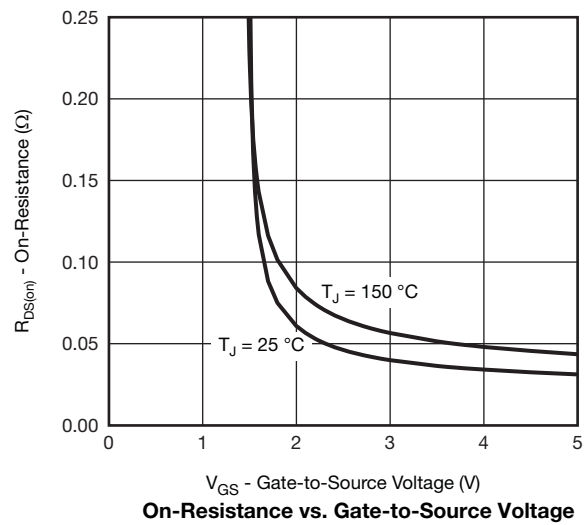
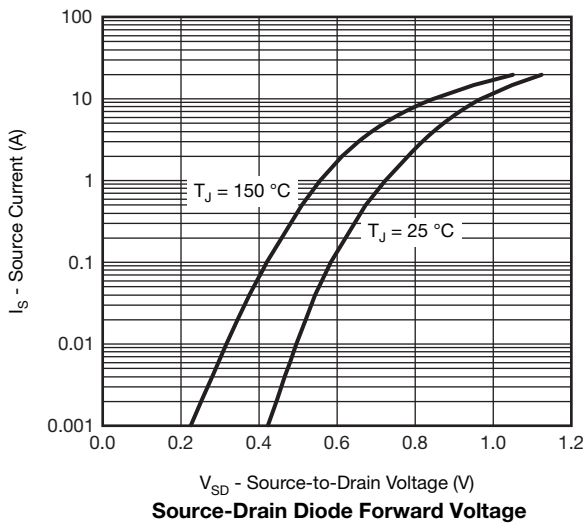
- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %.
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

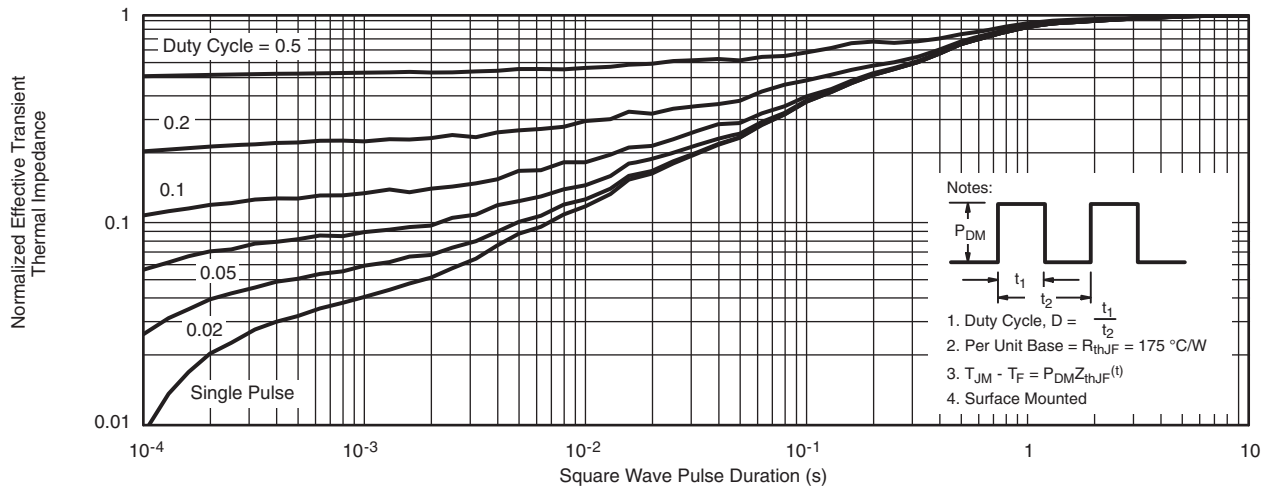
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



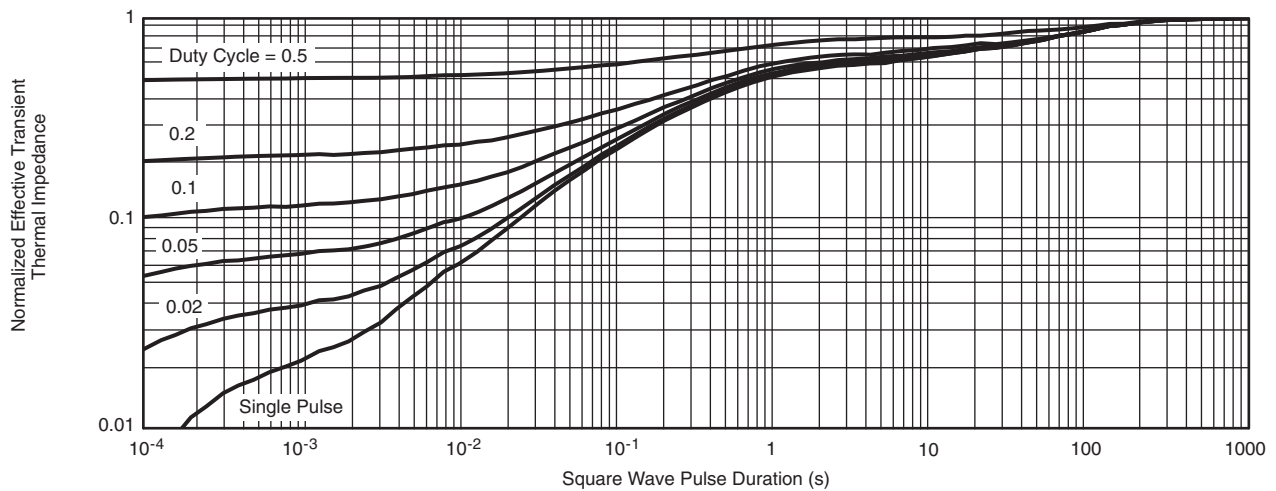
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot



Normalized Thermal Transient Impedance, Junction-to-Ambient

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^\circ\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Foot ($25\text{ }^\circ\text{C}$)
 are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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